

SC50-21YWA YELLOW

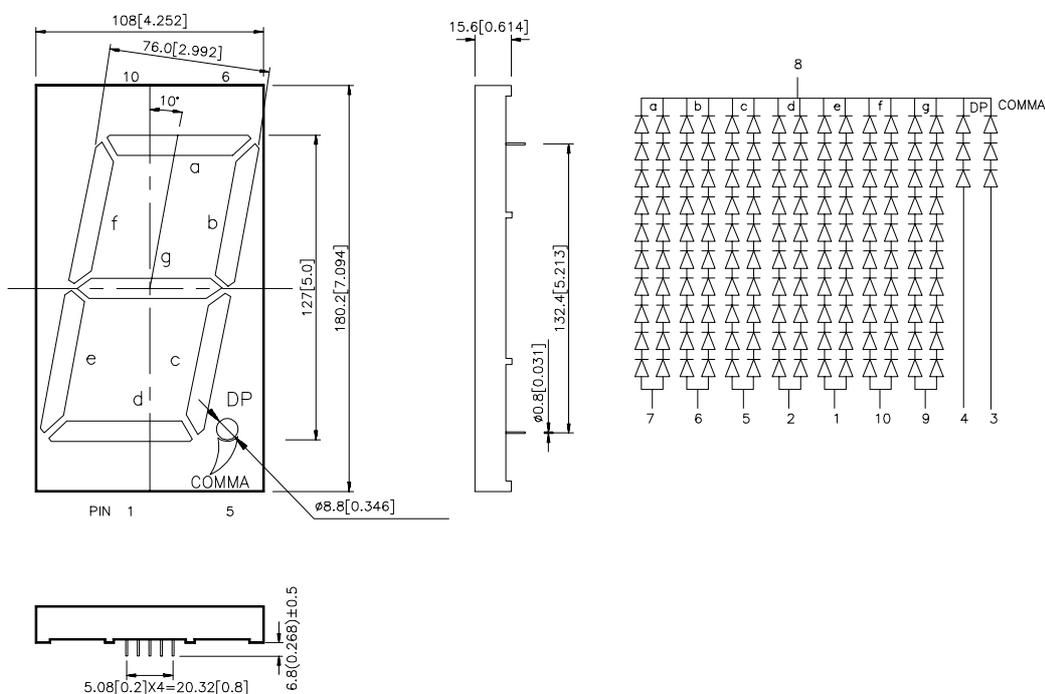
Features

- 0.50 INCH DIGIT HEIGHT.
- LOW CURRENT OPERATION.
- EXCELLENT CHARACTER APPEARANCE.
- EASY MOUNTING ON P.C. BOARDS OR SOCKETS.
- I.C. COMPATIBLE.
- CATEGORIZED FOR LUMINOUS INTENSITY.
- MECHANICALLY RUGGED.
- STANDARD : GRAY FACE, WHITE SEGMENT.

Description

The Yellow source color devices are made with Gallium Arsenide Phosphide on Gallium Phosphide Yellow Light Emitting Diode.

Package Dimensions & Internal Circuit Diagram



Notes:

1. All dimensions are in millimeters (inches), Tolerance is $\pm 0.25(0.01)$ unless otherwise noted.
2. Specifications are subject to change without notice.

Selection Guide

Part No.	Dice	Iv (ucd) @ 10 mA		Description
		Min.	Typ.	
SC50-21YWA	YELLOW (GaAsP/GaP)	3000	10500	Common Cathode,Rt.HandDecimal

Electrical / Optical Characteristics at T_A=25°C

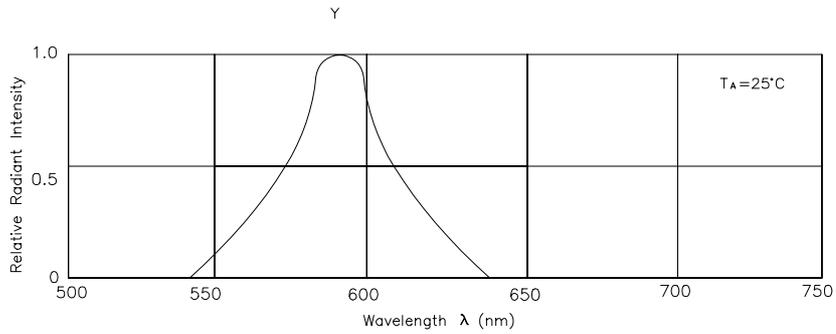
Symbol	Parameter	Device	Typ.	Max.	Units	Test Conditions
λ_{peak}	Peak Wavelength	Yellow	590		nm	IF=20mA
λ_D	Dominant Wavelength	Yellow	588		nm	IF=20mA
$\Delta\lambda_{1/2}$	Spectral Line Halfwidth	Yellow	35		nm	IF=20mA
C	Capacitance	Yellow	20		pF	VF=0V;f=1MHz
V _F	Forward Voltage	Yellow	2.1	2.5	V	IF=20mA
I _R	Reverse Current	Yellow		10	uA	VR = 5V

Absolute Maximum Ratings at T_A=25°C

Parameter	Yellow	Units
Power dissipation	105	mW
DC Forward Current	30	mA
Peak Forward Current [1]	140	mA
Reverse Voltage	5	V
Operating/Storage Temperature	-40°C To +85°C	
Lead Solder Temperature [2]	260°C For 5 Seconds	

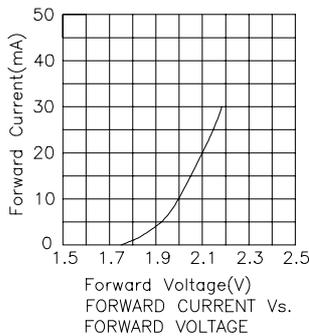
Notes:

- 1/10 Duty Cycle, 0.1ms Pulse Width.
- 4mm below package base.

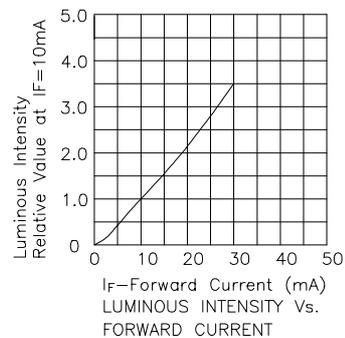


RELATIVE INTENSITY Vs. WAVELENGTH

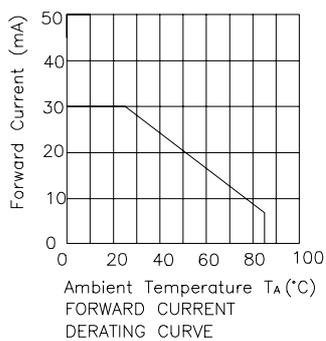
Yellow SC50-21YWA



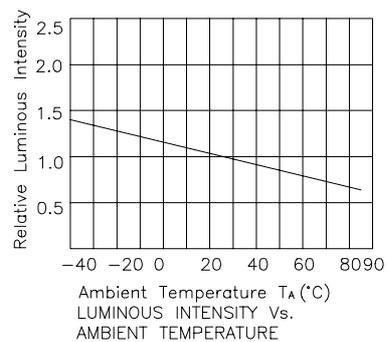
FORWARD CURRENT Vs. FORWARD VOLTAGE



LUMINOUS INTENSITY Vs. FORWARD CURRENT



FORWARD CURRENT DERATING CURVE



LUMINOUS INTENSITY Vs. AMBIENT TEMPERATURE